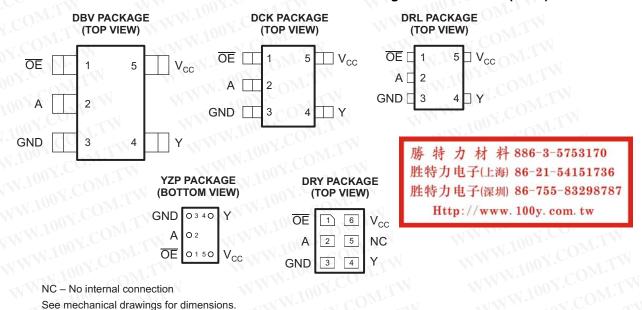


#### **FEATURES**

- Available in the Texas Instruments
   NanoStar<sup>™</sup> and NanoFree<sup>™</sup> Packages
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V
- Max t<sub>nd</sub> of 3.7 ns at 3.3 V
- Low Power Consumption, 10-μA Max Icc
- ±24-mA Output Drive at 3.3 V

- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



#### **DESCRIPTION/ORDERING INFORMATION**

This bus buffer gate is designed for 1.65-V to 5.5-V V<sub>CC</sub> operation.

The SN74LVC1G125 is a single line driver with a 3-state output. The output is disabled when the output-enable (OE) input is high.

NanoStar<sup>™</sup> and NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar, NanoFree are trademarks of Texas Instruments.

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# **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

#### ORDERING INFORMATION

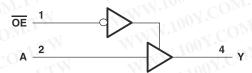
TA	PACKAGE <sup>(1)</sup>	COM.I	ORDERABLE PART NUMBER	TOP-SIDE MARKING(2)
.100 Y.CO.	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC1G125YZPR	CM
	SON - DRY	Reel of 5000	SN74LVC1G125DRYR	CM_
M. C.	COT (COT 22) DD)/	Reel of 3000	SN74LVC1G125DBVR	005
–40°C to 85°C	SOT (SOT-23) – DBV	Reel of 250	SN74LVC1G125DBVT	C25_
	00T (00 70) DOW	Reel of 3000	SN74LVC1G125DCKR	CONT.
	SOT (SC-70) – DCK	Reel of 250	SN74LVC1G125DCKT	CM_
	SOT (SOT-553) – DRL	Reel of 4000	SN74LVC1G125DRLR	CM_

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

INF	PUTS	OUTPUT
ŌĒ	A	YOW.
L	H	HOM.
L	L	1100 L COM
Н	X	Z

#### LOGIC DIAGRAM (POSITIVE LOGIC)



勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

WWW.100Y.COM.

<sup>(2)</sup> DBV/DCK/DRL/DRY: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



# **SN74LVC1G125** SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

# Absolute Maximum Ratings<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	COMPT	-0.5	6.5	V
V <sub>I</sub> 00	Input voltage range <sup>(2)</sup>	1001. COM. TW.	-0.5	6.5	V
Vo	Voltage range applied to any output in t	he high-impedance or power-off state (2)	-0.5	6.5	V
Vo	Voltage range applied to any output in t	he high or low state (2)(3)	-0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0	Too C	-50	mA
lok	Output clamp current	V <sub>O</sub> < 0	$N.100^{-1}$	-50	mA
lo	Continuous output current	W. TOOY.CO. TW	100 Y.	±50	mA
TWV	Continuous current through V <sub>CC</sub> or GNI	DNW. TO COME	M	±100	√ mA
11	N.1001.	DBV package	Milan	206	-XX
		DCK package	100	252	
$\theta_{JA}$	Package thermal impedance (4)	DRL package	111	142	°C/W
		DRY package	WWW	234	
		YZP package	· WW.	132	
T <sub>stg</sub>	Storage temperature range	W. 1001.	-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The value of V<sub>CC</sub> is provided in the recommended operating conditions table.

The package thermal impedance is calculated in accordance with JESD 51-7.

# SN74LVC1G125 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT





# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
,	CONSTRUCTION	Operating	1.65	5.5	V
$V_{CC}$	Supply voltage	Data retention only	1.5		V
100	Y.C. TIN	V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	M.I.	
	MILEON WW	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	TIM	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V	2	WT	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	$0.7 \times V_{CC}$	OM	
- 41	100Y.COMITW	V <sub>CC</sub> = 1.65 V to 1.95 V	W.100 1	$0.35 \times V_{CC}$	r
	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1007	0.7	V
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V	WW.	0.8	N V
		V <sub>CC</sub> = 4.5 V to 5.5 V	M.Inc	$0.3 \times V_{CC}$	
VI	Input voltage	1001. ON:IN	0	5.5	V
Vo	Output voltage	WWW. TOOX.CO. T.T.	0	V <sub>cc</sub>	V
4	MM.Ing COMP.	V <sub>CC</sub> = 1.65 V	WWW	.C -4	WT.
		V <sub>CC</sub> = 2.3 V	TWW.	-8	
ОН	High-level output current	V 2V 1001.	N TAN	-16	mA
		V <sub>CC</sub> = 3 V	MM	-24	
		V <sub>CC</sub> = 4.5 V	WW	-32	
	M. 1001. OM.T.	V <sub>CC</sub> = 1.65 V		4	OM.
		V <sub>CC</sub> = 2.3 V	111	1008	
OL	Low-level output current	W v avery on v. Co.	W	16	mA
		V <sub>CC</sub> = 3 V	I «X	24	
		V <sub>CC</sub> = 4.5 V	-7	32	
	MM	$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$	N 4	20	O.A.
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	CW	10	ns/V
		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5	
ΓΑ	Operating free-air temperature	M. I.M. M. 21 100 J.	-40	85	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



# WWW.100Y.COM. SN74LVC1G125 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP <sup>(1)</sup> MAX	ι
	$I_{OH} = -100 \mu\text{A}$	1.65 V to 5.5 V	V <sub>CC</sub> - 0.1	DIAT.	
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2	OM.I	
V. OOY.CU	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9	WI.IV	
V <sub>OH</sub>	I <sub>OH</sub> = -16 mA	3 V	2.4	CONTIN	
	$I_{OH} = -24 \text{ mA}$	3 V	2.3	COM	
	$I_{OH} = -32 \text{ mA}$	4.5 V	3.8	COMIT	
WW.	$I_{OL} = 100 \mu A$	1.65 V to 5.5 V	100	0.1	
	I <sub>OL</sub> = 4 mA	1.65 V	WWW.	0.45	
V 100	I <sub>OL</sub> = 8 mA	2.3 V	T.WW.I	0.3	
V <sub>OL</sub>	I <sub>OL</sub> = 16 mA	2.1/	0.4 0.55		
	I <sub>OL</sub> = 24 mA	3 V			
WW.1	I <sub>OL</sub> = 32 mA	4.5 V	WWW	0.55	
I <sub>I</sub> A or OE inputs	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V	WW	N.100Y.C±5	\1.
I <sub>off</sub>	$V_I$ or $V_O = 5.5 \text{ V}$	CONO	WW	±10	17.
I <sub>OZ</sub>	$V_0 = 0 \text{ to } 5.5 \text{ V}$	3.6 V	-1	10	$O_J$
I <sub>cc</sub>	$V_{I} = 5.5 \text{ V or GND}, \qquad I_{O} = 0$	1.65 V to 5.5 V		10	40
Δl <sub>CC</sub>	One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	3 V to 5.5 V	V	500	
Cı	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V	N	4	C

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. WWW.100Y.COM.

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# SN74LVC1G125 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

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#### **Switching Characteristics**

over recommended operating free-air temperature range, C<sub>I</sub> = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V <sub>CC</sub> = 1.8 V ± 0.15 V	V <sub>CC</sub> = 2.5 V ± 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V	V <sub>CC</sub> = 5 V ± 0.5 V	UNIT
LOOY.CO	(INPUT)	(OUTPUT)	MIN MAX	MIN MAX	MIN MAX	MIN MAX	
t <sub>pd</sub>	A	Y	1.9 6.9	0.7 4.6	0.6 3.7	0.5 3.4	ns

## **Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 30 pF or 50 pF (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO	V <sub>CC</sub> = ± 0.1	1.8 V 5 V	V <sub>CC</sub> = ± 0.2		V <sub>CC</sub> = ± 0.3	3.3 V 3 V	V <sub>CC</sub> = ± 0.5	5 V 5 V	UNIT
1 100 Y	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	N
t <sub>pd</sub>	Α	Y	2.8	9	1.2	5.5	1	4.5	1	4	ns
t <sub>en</sub>	ŌE	Y	3.3	10.1	1.5	6.6	1	5.3	1	5	ns
t <sub>dis</sub>	ŌĒ	Y	1.3	9.2	1	5	1	5	1.C	4.2	ns

## **Operating Characteristics**

PARAME		ED M.TW	TEST	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	V <sub>CC</sub> = 5 V	UNIT	
	PARAMETER		CONDITIONS	TYP	TYP	TYP	TYP	OINII	
C	Power dissipation	Outputs enabled	f = 10 MHZ	18	18	19	21	COR	
$C_{pd}$	capacitance	Outputs disabled	I = IU WINZ	2	2	2	4	pF	

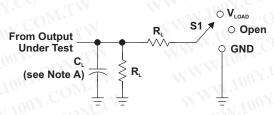
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**SN74LVC1G125** 



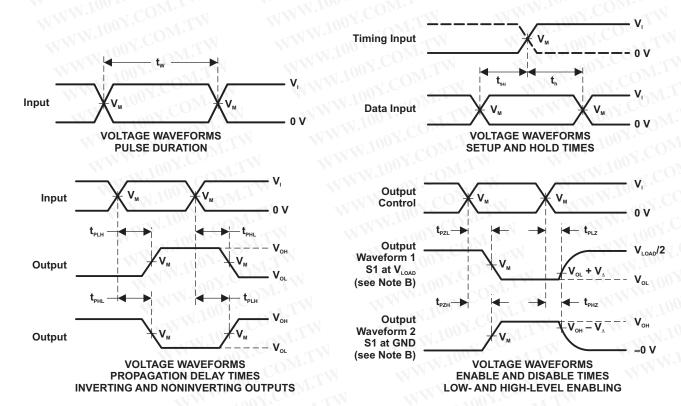
#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
$t_{PHZ}/t_{PZH}$	GND

LOAD CIRCUIT

WIN	IN	PUTS		1.7	- //	1	00 1.
V <sub>cc</sub>	Vi	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	C <sup>r</sup>	R <sub>L</sub>	V
1.8 V ± 0.15 V	V <sub>cc</sub>	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	15 pF	1 ΜΩ	0.15 V
$2.5~\textrm{V}~\pm~0.2~\textrm{V}$	$V_{cc}$	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	15 pF	1 MΩ	0.15 V
$3.3 \text{ V} \pm 0.3 \text{ V}$	3 V	≤2.5 ns	1.5 V	6 V	15 pF	<b>1 M</b> Ω	0.3 V
5 V ± 0.5 V	$V_{cc}$	≤2.5 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	15 pF	1 ΜΩ	0.3 V



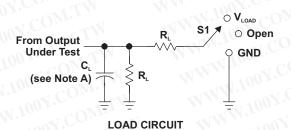
NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics:  $PRR \le 10 \text{ MHz}$ ,  $Z_0 = 50 \Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{\mbox{\tiny PZL}}$  and  $t_{\mbox{\tiny PZH}}$  are the same as  $t_{\mbox{\tiny en}}.$
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



## PARAMETER MEASUREMENT INFORMATION (continued)



5 V ± 0.5 V

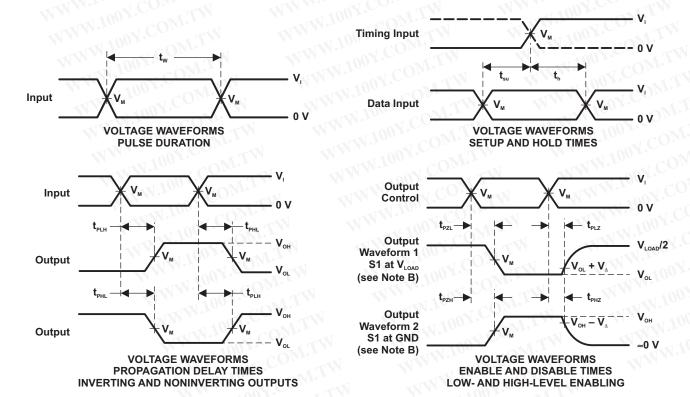
TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	<b>V</b> <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

**500** Ω

0.3 V

50 pF

WIII	IN	PUTS 1	cO1	1.1.		TAXIN.	
V <sub>cc</sub>	V <sub>i</sub>	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	C <sub>L</sub>	R <sub>L</sub>	V <sub>A</sub>
1.8 V ± 0.15 V	V <sub>cc</sub>	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	30 pF	1 kΩ	0.15 V
$2.5 V \pm 0.2 V$	$V_{cc}$	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	30 pF	500 Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics:  $PRR \le 10 \text{ MHz}$ ,  $Z_0 = 50 \Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{\mbox{\tiny PZL}}$  and  $t_{\mbox{\tiny PZH}}$  are the same as  $t_{\mbox{\tiny en}}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms



## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp (3)
74LVC1G125DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G125DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G125DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G125DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G125DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G125DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G125DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G125DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G125DRYRG4	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G126DBVTE4	ACTIVE	SOT-23	DBV	50	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G125DBVR	ACTIVE	SOT-23	DBV	50	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G125DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G125DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G125DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G125DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G125DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G125YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.





18-Sep-2008

retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC1G125:

Automotive: SN74LVC1G125-Q1

Enhanced Product: SN74LVC1G125-EP

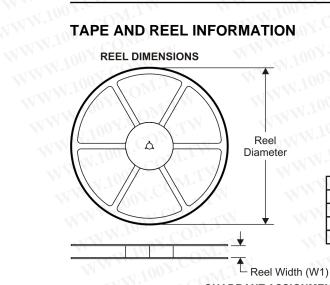
NOTE: Qualified Version Definitions:

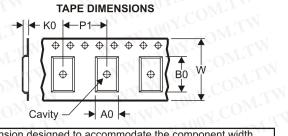
- WWW.100Y.COM.TW Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

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## PACKAGE MATERIALS INFORMATION

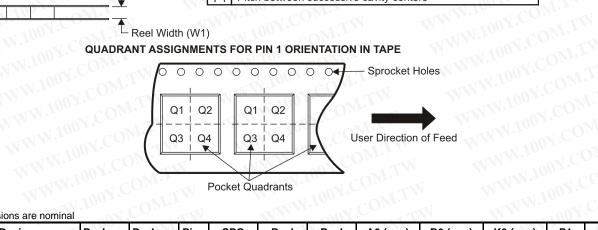
4-Dec-2008





V	A0	Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
V		Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
	P1	Pitch between successive cavity centers

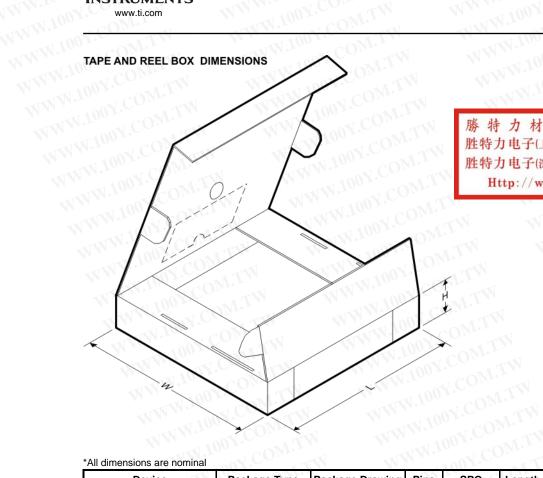
## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device Property of the control of th	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadran
SN74LVC1G125DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G125DBVR	SOT-23	DBV	5	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G125DBVT	SOT-23	DBV	5	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G125DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G125DCKR	SC70	DCK	5	3000	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74LVC1G125DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G125DCKT	SC70	DCK	5	250	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74LVC1G125DRLR	SOT	DRL	5	4000	180.0	9.2	1.78	1.78	0.69	4.0	8.0	Q3
SN74LVC1G125DRYR	SON	DRY	6	5000	179.0	8.4	1.2	1.65	0.7	4.0	8.0	Q1
SN74LVC1G125YZPR	DSBGA	YZP	5	3000	180.0	8.4	1.02	1.52	0.66	4.0	8.0	Q1
SN74LVC1G125YZPR	DSBGA	YZP	5	3000	180.0	8.4	1.02	1.52	0.66	4.0	8.0	Q1

## PACKAGE MATERIALS INFORMATION

4-Dec-2008



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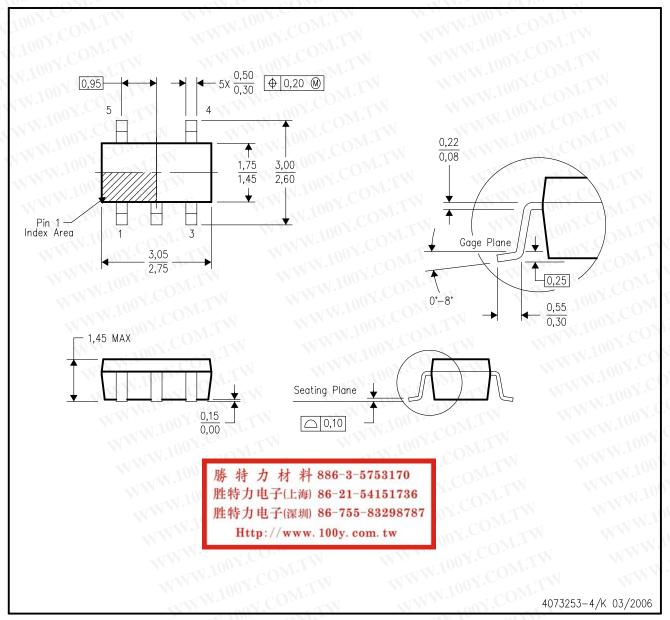
MMM-Inc

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins 5	<b>SPQ</b> 3000	Length (mm)	Width (mm) 140.0	Height (mm) 75.0
SN74LVC1G125DBVR	SOT-23	DBV			565.0		
SN74LVC1G125DBVR	SOT-23	DBV	5	3000	205.0	200.0	33.0
SN74LVC1G125DBVT	SOT-23	DBV	5	250	205.0	200.0	33.0
SN74LVC1G125DCKR	SC70	DCK	5	3000	565.0	140.0	75.0
SN74LVC1G125DCKR	SC70	DCK	5	3000	205.0	200.0	33.0
SN74LVC1G125DCKT	SC70	DCK	5	250	565.0	140.0	75.0
SN74LVC1G125DCKT	SC70	DCK	5	250	205.0	200.0	33.0
SN74LVC1G125DRLR	SOT	DRL	5	4000	202.0	201.0	28.0
SN74LVC1G125DRYR	SON	DRY	6	5000	220.0	205.0	50.0
SN74LVC1G125YZPR	DSBGA	YZP	5	3000	220.0	220.0	34.0
SN74LVC1G125YZPR	DSBGA	YZP	5	3000	220.0	220.0	34.0

# DBV (R-PDSO-G5)

# PLASTIC SMALL-OUTLINE PACKAGE



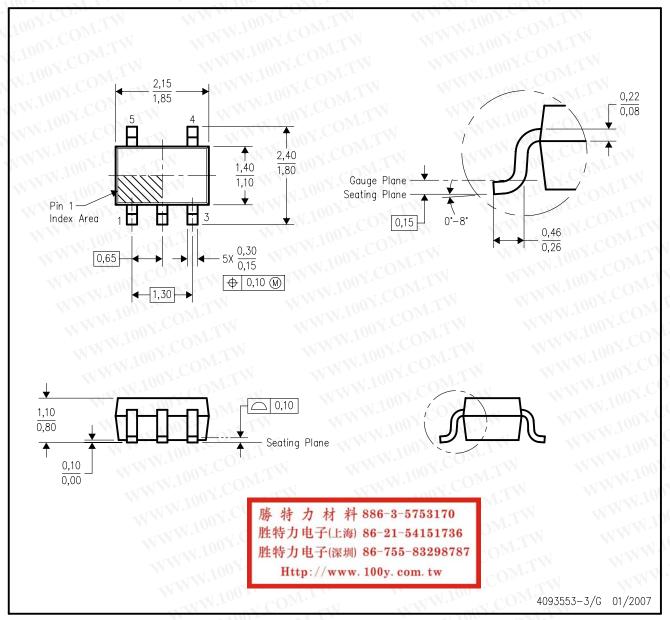
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-178 Variation AA.



# DCK (R-PDSO-G5)

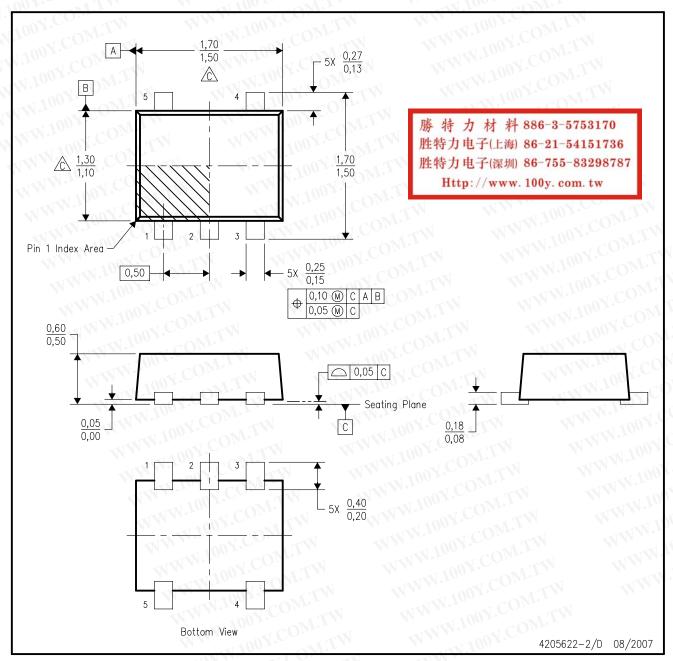
# PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



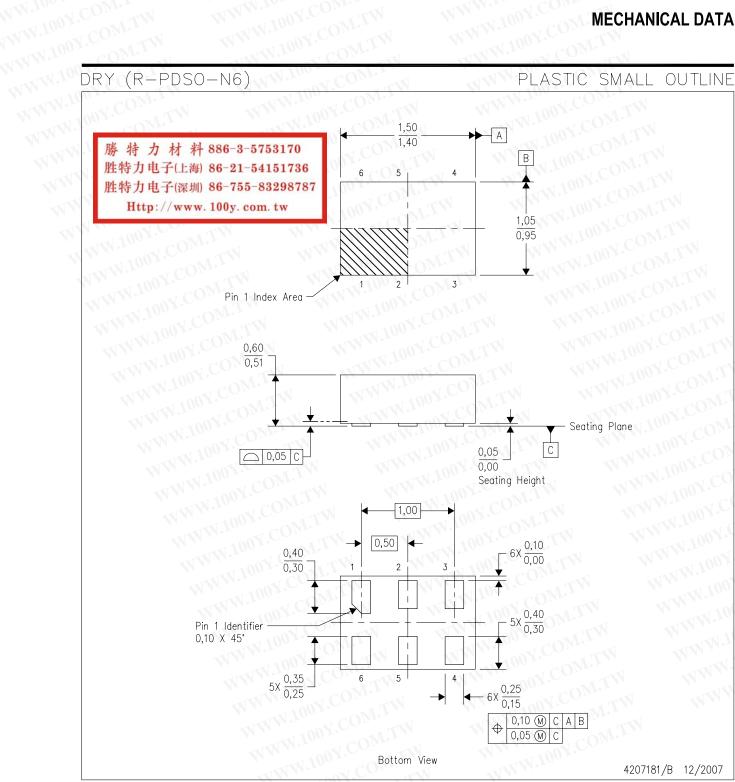


NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

  Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.





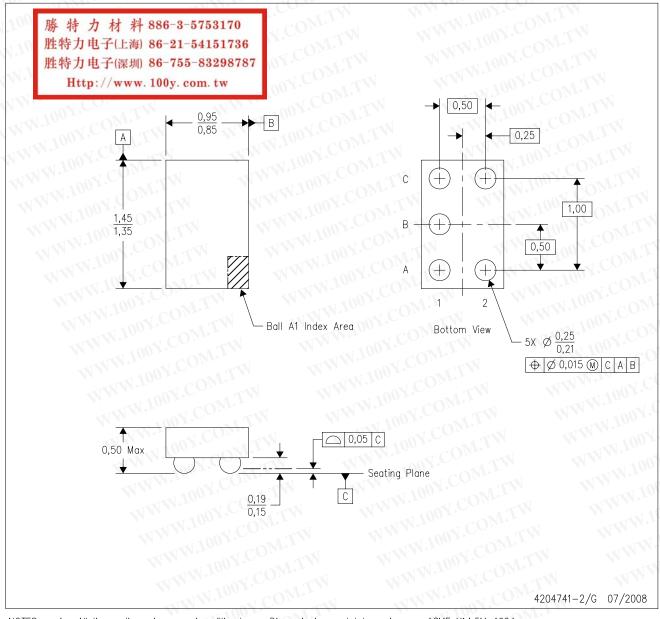
NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- В. This drawing is subject to change without notice.
- SON (Small Outline No-Lead) package configuration.
- This package complies to JEDEC MO-287 variation UFAD.



YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead—free. Refer to the 5 YEP package (drawing 4204725) for tin—lead (SnPb).

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